



DMT6016LFDF

## **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I <sub>D Max</sub> T <sub>A</sub> = +25°C
60V	16mΩ @ V <sub>GS</sub> = 10V	8.9A
000	$27m\Omega @ V_{GS} = 4.5V$	6.8A

#### Description

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

- Load Switch
- Adaptor Switch
- Notebook PC

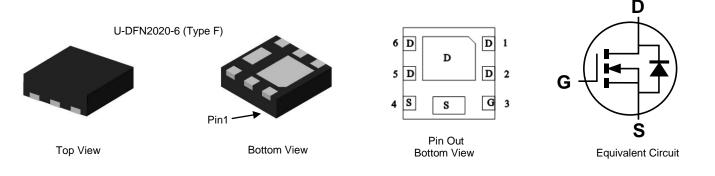
#### 60V N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features and Benefits**

- 100% Unclamped Inductive Switch (UIS) Test in Production
- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm<sup>2</sup>
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: U-DFN2020-6 (Type F)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.007 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Quantity per Reel
DMT6016LFDF-7	T6	7	3,000
DMT6016LFDF-13	Т6	13	10,000

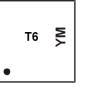
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



T6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: B = 2014) M = Month (ex: 9 = September)

#### Date Code Key

Notes:

Year	201	4	2015		2016	20	17	2018		2019	2	2020
Code	В		С		D			F		G		Н
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	60	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	8.9 7.1	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	11.1 8.9	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	60	А	
Maximum Body Diode Continuous Current	Is	2.2	А		
Avalanche Current (Note 7) L = 0.1mH	I <sub>AS</sub>	15.3	А		
Avalanche Energy (Note 7) L = 0.1mH	E <sub>AS</sub>	11.7	mJ		

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Dowar Dissinction (Note 5)	T <sub>A</sub> = +25°C	Р	0.82	W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	PD	0.52	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Р	153	°C/W
memai Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	97	
Total Dowar Dissinction (Note 6)	T <sub>A</sub> = +25°C	Р	1.9	W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	PD	1.2	
Thermal Registeres, Junction to Ambient (Note 6)	Steady State	D	66	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R <sub>0JA</sub>	42	
Thermal Resistance, Junction to Case (Note 6)	R <sub>θJC</sub>	14.7		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

			I		I	1
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)					1	1
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60		_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_		1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0		3.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance		_	2	16	mΩ	$V_{GS} = 10V, I_D = 10A$
	R <sub>DS(ON)</sub>	_	17.2	27	11152	$V_{GS} = 4.5V, I_D = 6A$
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		864	—		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1.0MHz
Output Capacitance	Coss	_	282		pF	
Reverse Transfer Capacitance	Crss	_	27.1			
Gate Resistance	R <sub>g</sub>		1.35		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	17			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	8.4		nC	V <sub>DS</sub> = 30V. I <sub>D</sub> = 10A
Gate-Source Charge	Q <sub>gs</sub>		3.1		ne	$v_{\rm DS} = 30$ v, $i_{\rm D} = 10$ A
Gate-Drain Charge	Q <sub>gd</sub>		4.3			
Turn-On Delay Time	t <sub>D(ON)</sub>		3.4			
Turn-On Rise Time	t <sub>R</sub>	_	5.2	—	nS	$V_{GS} = 10V, V_{DD} = 30V, R_g = 6\Omega,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	12.9		113	I <sub>D</sub> = 10A
Turn-Off Fall Time	tF	_	6.8		1	
Body Diode Reverse Recovery Time	t <sub>RR</sub>		22		nS	I <sub>S</sub> = 10A, dl/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	11.1		nC	I <sub>S</sub> = 10A, dl/dt = 100A/µs

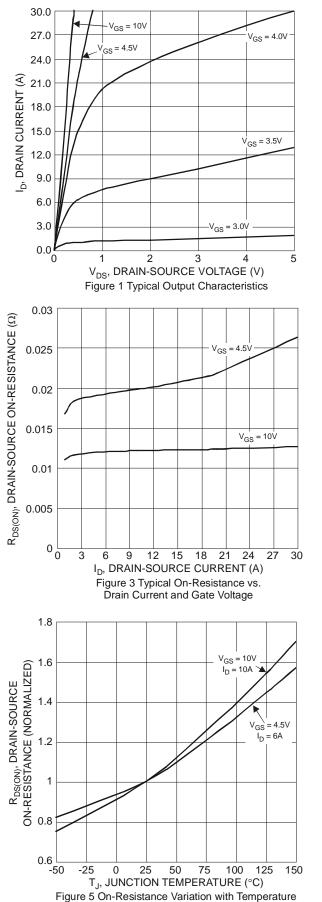
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. 7.  $I_{AS}$  and  $E_{AS}$  rating are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}$ C. Notes:

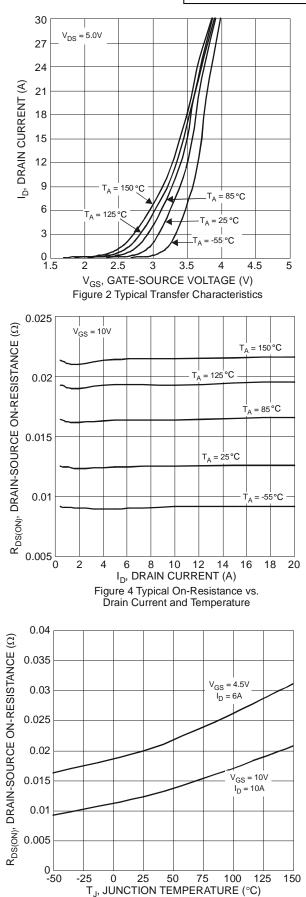
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

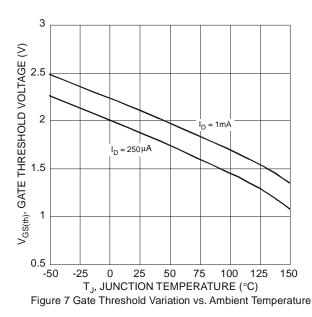












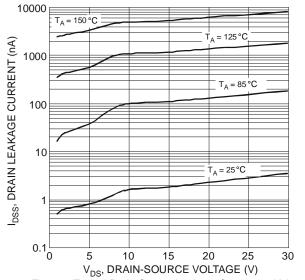
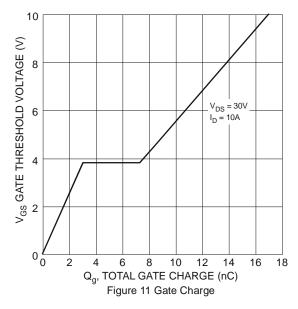
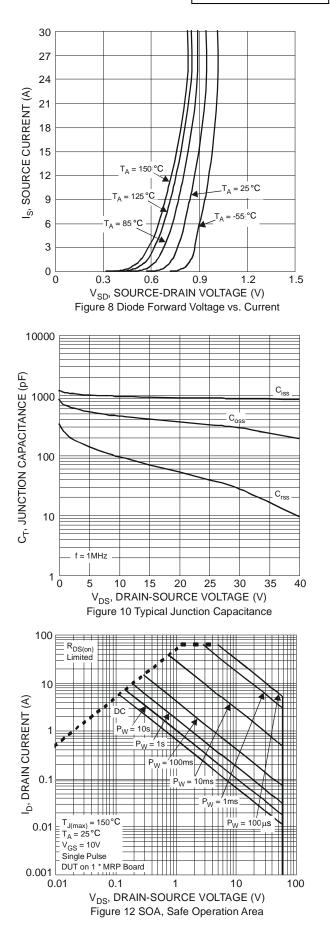
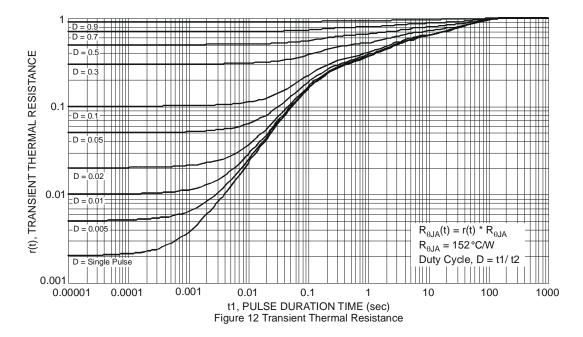


Figure 9 Typical Drain-Source Leakage Current vs. Voltage





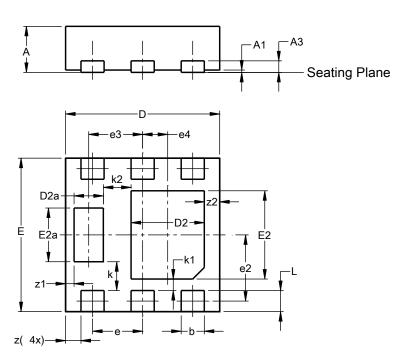






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



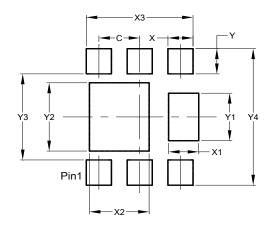
U-DFN2020-6 (Type F)								
Dim	Min	Max	Тур					
Α	0.57	0.63	0.60					
A1	0.00	0.05	0.03					
A3	-	0.1						
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
E	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
е		0.65 BSC						
e2	(	).863 BS	SC					
e3		0.70 BS	С					
e4		).325 BS						
k		0.37 BS	С					
k1		0.15 BS						
k2		0.36 BS	С					
L	0.225	0.325	0.275					
z		0.20 BS						
z1	(	).110 BS	SC					
z2		0.20 BSC						
	Dimens	ions in	mm					

#### U-DFN2020-6 (Type F)

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-6 (Type F)



Dimensions	Value
Dimensions	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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